Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.450 inches	
Overall Diameter:	
0.667 inches	
Mounting Facility Quantity:	
1	
Joint Electronic Device Engineering Council/jedec/case Outline Designation	ation:
Do-5	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed case	
Overall Width Across Flats:	
Between 0.667 inches and 0.687 inches	
Thread Size:	
0.250 inches	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
500.0 reverse voltage, peak	
Current Rating Per Characteristic:	
900.00 amperes forward current, average absolute	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
1 threaded stud and 1 tab, solder lug	
Specification Data:	
80131-release3138 professional/industrial association specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	
Fiig:	